



Mid-circuit measurement on $^{171}\text{Yb}^+$ using the *omg* architecture

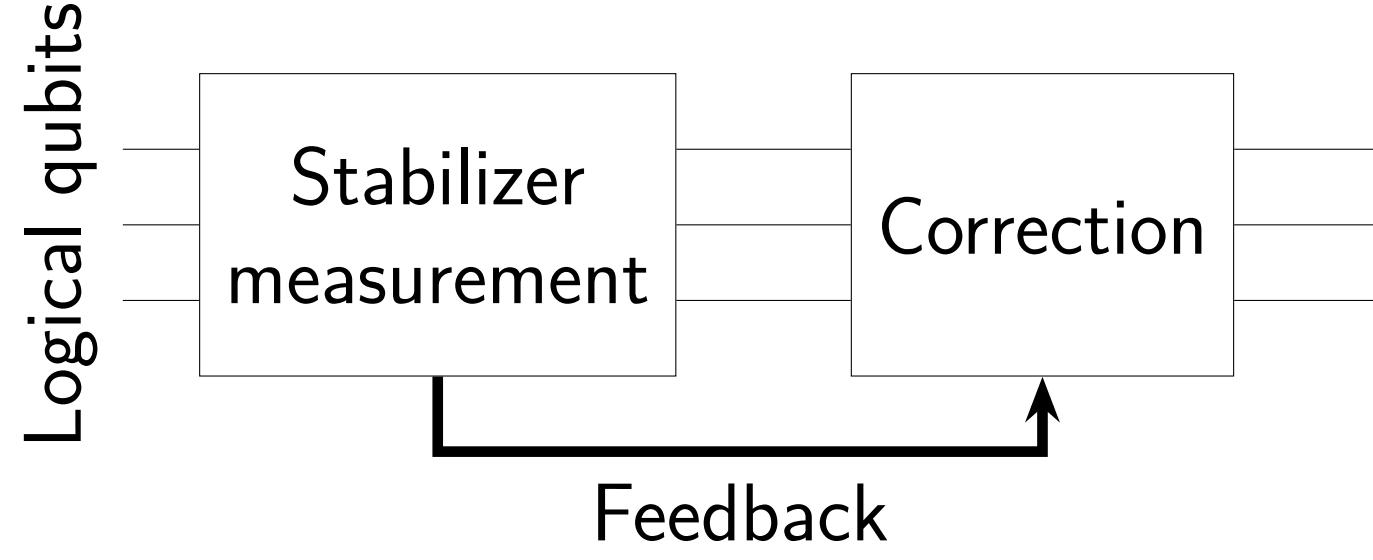
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Mid-circuit measurement and the *omg* architecture

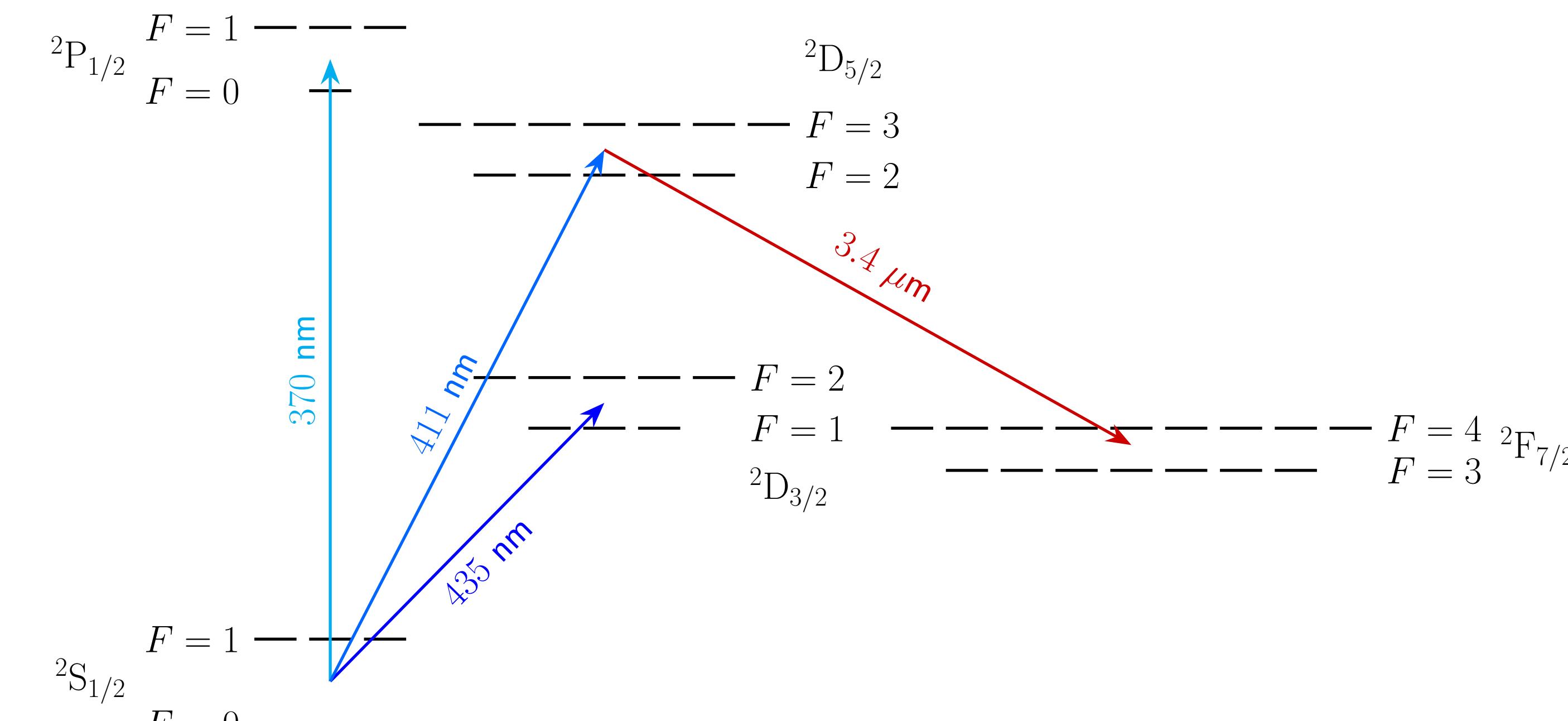
Mid-circuit measurement

- Required for multiple rounds of error correction
- Partial readout without perturbing the rest of the system



omg architecture

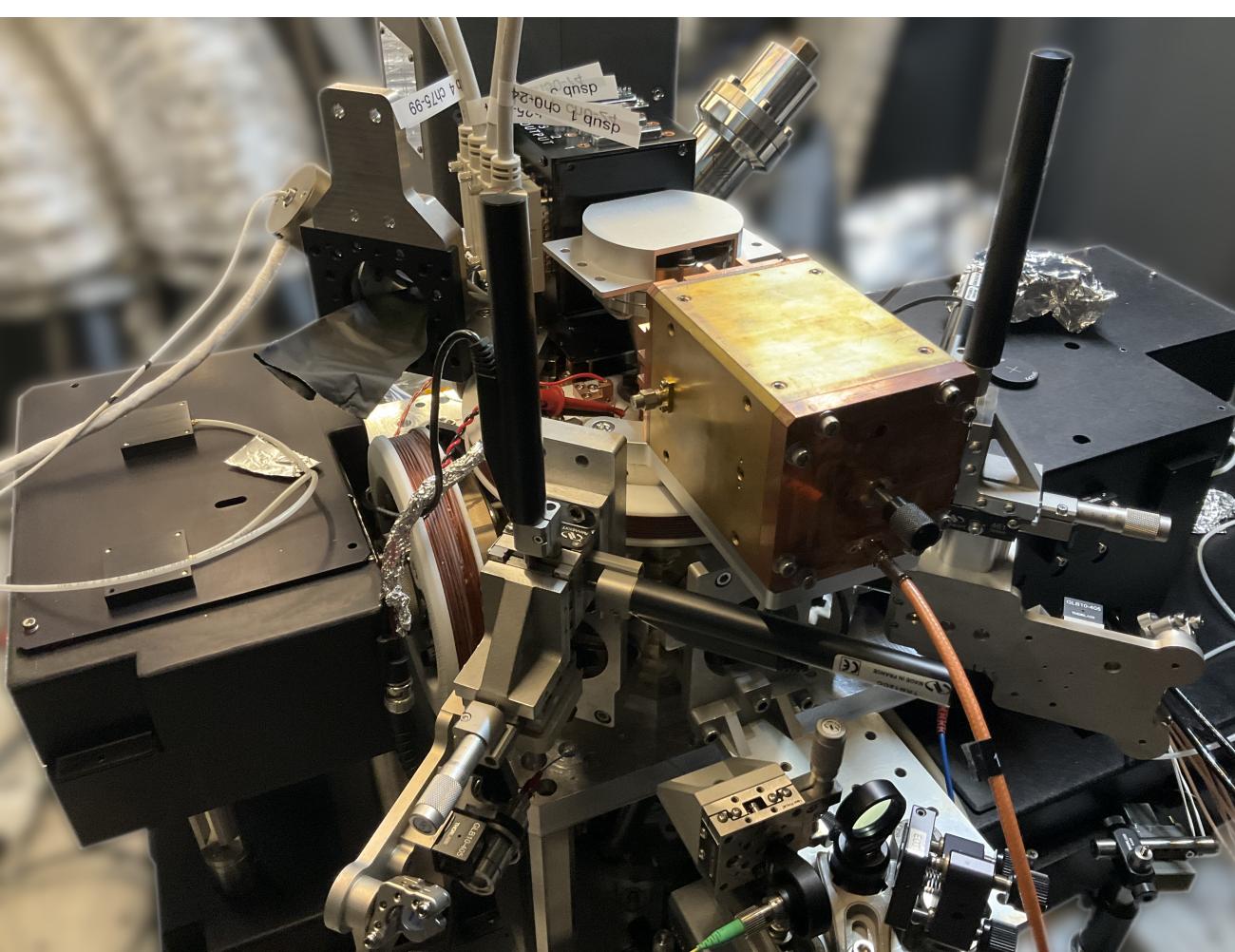
- Combining **O**ptical **M**etastable and **G**round state qubits
- Protecting quantum information by converting between qubit types
- Faster than ion-shuttling



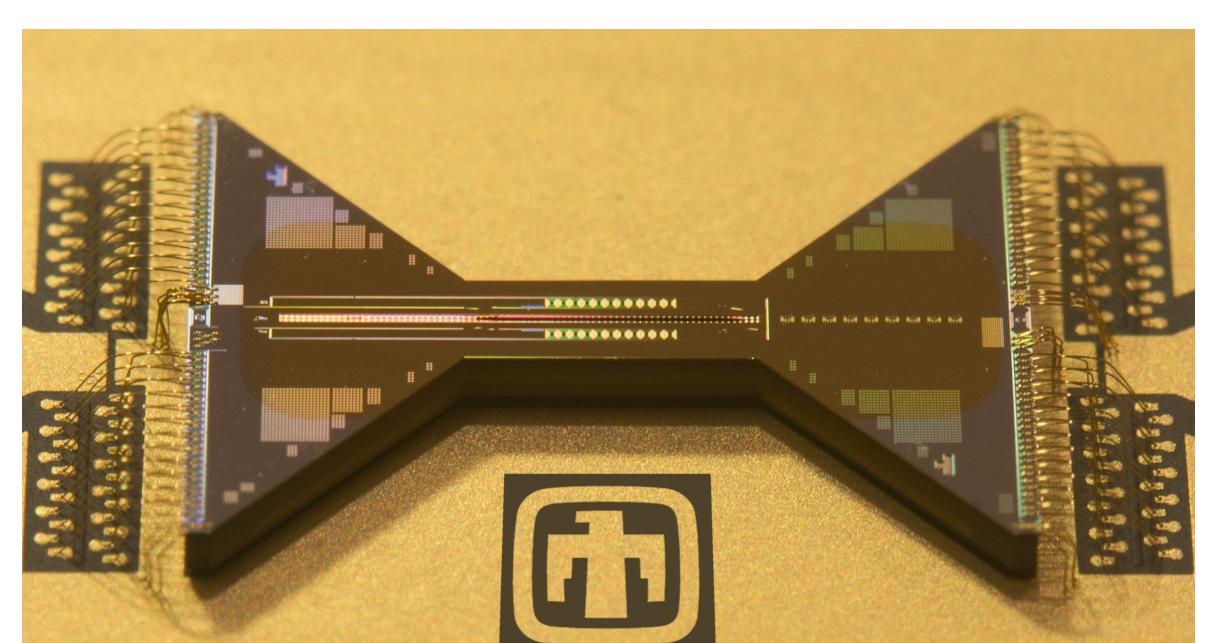
System

Optical control

- Global state preparation and detection with 370 nm
- Individually addressable Raman with 355 nm
- Global 435 nm for exciting to $D_{3/2}$ states
- (Planned) Global 411 nm and 3.4 μm for accessing $D_{5/2}$ and $F_{7/2}$ states

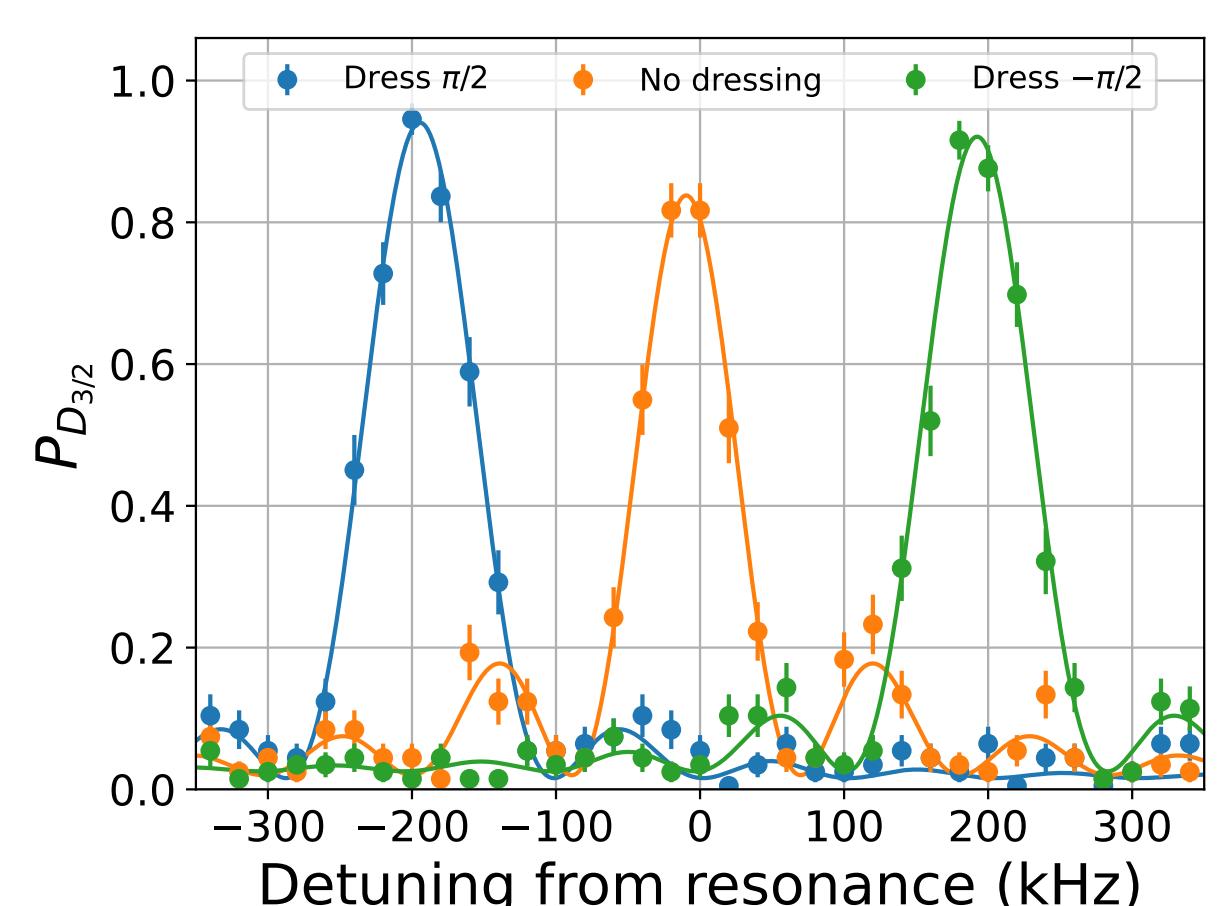
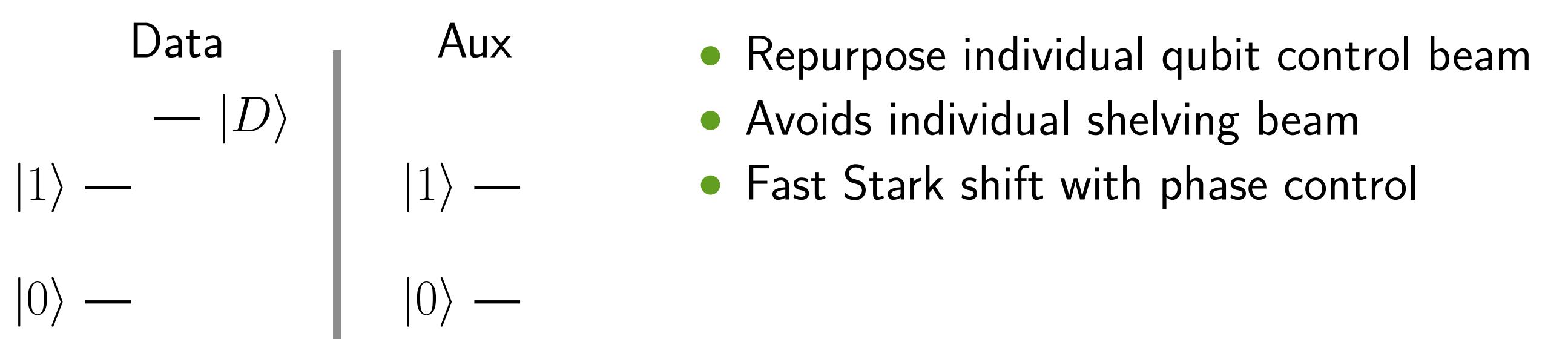


Phoenix surface trap



- Separate loading and quantum region
- Fine control of ion position
- Low heating rate

Selective shelving with Raman dressing



Miniaturized 369/399/780/935nm Beam Path